
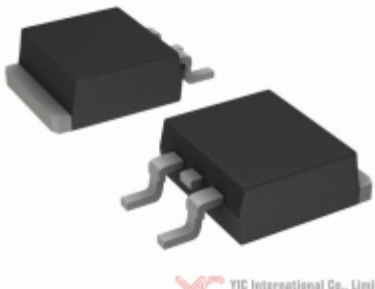



	<h2 style="color: red;">FQB12P10TM</h2> <p>Hersteller-Teilenummer: FQB12P10TM</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET P-CH 100V 11.5A D2PAK</p> <hr/> <p>Datenblätter:  FQB12P10TM.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 32363 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB12P10TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 100V 11.5A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 75W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	11.5A (Tc)
Rds On (Max) @ Id, Vgs	290 mOhm @ 5.75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	27nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	800pF @ 25V
Verpackung	Tape & Reel (TR)













































FQB12P10TM ist neu im Original, Suche FQB12P10TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB12P10TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB12P10TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB12N60TM_AM002 Fairchild/ON Semiconductor MOSFET N-CH 600V 10.5A D2PAK</p>	 <p>FQB12P10 FSC FQB12P10 FSC</p>	 <p>FQB12N60TM Fairchild/ON Semiconductor FQB12N60TM FAIRCHILD</p>	 <p>FQB12P20TM Fairchild/ON Semiconductor MOSFET P-CH 200V 11.5A D2PAK</p>
 <p>FQB12P20 FSC FQB12P20 FSC</p>	 <p>FQB12P10TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 11.5A D2PAK</p>	 <p>FQB12N60CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 12A D2PAK</p>	 <p>FQB13N06L F FQB13N06L F</p>

heiße Teile

Mehr

 FQB10N60C	 FQB10N60CTM	 FQB10N60CTM	D FQB11N40	 FQB11N40C
 FQB11N40CTM	 FQB11N40CTM	D FQB11N60FTM	 FQB11N60TM	 FQB11P06
 FQB11P06TM	 FQB11P06TM	 FQB11P06TM**CN-SCI	 FQB12N50TM	 FQB12N50TM_AM002
D FQB12N50TM_AM002	 FQB12N60	 FQB12N60C	 FQB12N60CTM	 FQB12N60CTM
 FQB12N60TM	 FQB12N60TM_AM002	 FQB12N60TM_AM002	 FQB12P10	 FQB12P10TM
 FQB12P20	 FQB12P20TM	D FQB12P20TM	 FQB13N06L	 FQB13N10
 FQB13N10L	D FQB13N50	 FQB13N50CTM	 FQB13N50CTM	 FQB140N03L
 FQB14N30TM	 FQB14N30TM	 FQB16N25TM	 FQB16N25TM	 FQB17P06
 FQB17P10	 FQB17P10TM	 FQB17P10TM	D FQB19N10L	 FQB19N10LTM
 FQB19N10LTM	 FQB19N10TM	 FQB19N10TM	 FQB19N20	 FQB19N20C

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited